

August 1998 Revised January 2005

GTLP16T1655 16-Bit LVTTL/GTLP Universal Bus Transceiver with High Drive GTLP and Individual Byte Controls

General Description

The GTLP16T1655 is a 16-bit universal bus transceiver that provides LVTTL to GTLP signal level translation. It allows for transparent, latched and clocked modes of data transfer. The device provides a high speed interface between cards operating at LVTTL logic levels and a backplane operating at GTLP logic levels. High speed backplane operation is a direct result of GTLP's reduced output swing (<1V), reduced input threshold levels and output edge rate control. The edge rate control minimizes bus settling time. GTLP is a Fairchild Semiconductor derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD8-3.

Fairchild's GTLP has internal edge-rate control and is process, voltage, and temperature (PVT) compensated. Its function is similar to BTL and GTL but with different output levels and receiver threshold. GTLP output LOW level is typically less than 0.5V, the output level HIGH is 1.5V and the receiver threshold is 1.0V.

Features

- Bidirectional interface between GTLP and LVTTL logic levels
- Variable edge rate control pin to select desired edge rate on the GTLP backplane (V_{ERC})
- V_{REF} pin provides external supply reference voltage for receiver threshold adjustibility
- Special PVT compensation circuitry to provide consistent performance over variations of process, supply voltage and temperature
- TTL compatible driver and control inputs
- Designed using Fairchild advanced BiCMOS technology
- Bushold data inputs on A port to eliminate the need for external pull-up resistors for unused inputs
- Power up/down and power off high impedance for live insertion
- Open drain on GTLP to support wired-or connection
- Flow through pinout optimizes PCB layout
- D-type flip-flop, latch and transparent data paths
- A Port source/sink -24mA/+24mA
- B Port sink +100mA
- Partitioned as two 8-bit transceivers with individual latch timing and output control but with a common clock
- External pin to pre-condition I/O capacitance to high state (V_{CCBIAS})

Ordering Code:

Order Number	Package Number	Package Description
GTLP16T1655MTD	MTD64	64-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

10EAB	1	64	-CLK
10EBA	2	63	-1LEAB
V _{CC} -	3	62	-1LEBA
1A1-	4	61	-Verc
GND-	5	60	-GND
1A2-	6	59	−1B1
1A3-	7	58	-1B2
GND-	8	57	-GND
1A4-	9	56	-1B3
GND-	10	55	− 1B4
1A5-	11	54	– 1B5
GND-	12	53	-GND
1A6-	13	52	-1B6
1A7-	14	51	-1B7
Vcc-	15	50	-Vcc
1A8-	16	49	-1B8
2A1-	17	48	-2B1
GND-	18	47	-GND
2A2-	19	46	-2B2
2A3-	20	45	-2B3
GND-	21	44	-GND
2A4-	22	43	-2B4
2A5-	23	42	-2B5
GND-	24	41	-V _{REF}
2A6-	25	40	− 2B6
GND-	26	39	-GND
2A7-	27	38	-2B7
Vcc-	28	37	-2B8
2A8-	29	36	-VCCBIAS
GND-	30	35	-2LEAB
2OEAB	31	34	-2LEBA
20EBA -	32	33	-OE

Pin Descriptions

Pin Names	Description
1 OEAB	A-to-B Output Enable (Active LOW)
2OEAB	Byte 1 and Byte 2
1 OEBA	B-to-A Output Enable (Active LOW)
2OEBA	Byte 1 and Byte 2
ŌE	Disables all I/O ports simultaneously
1LEAB	A-to-B Latch Enable (Transparent HIGH)
2LEAB	Byte 1 and Byte 2
1LEBA	B-to-A Latch Enable (Transparent HIGH)
2LEBA	Byte 1 and Byte 2
V_{REF}	GTLP Reference Voltage
CLK	A-to-B and B-to-A Clock
1A1-1A8	A Port I/O Byte 1 and Byte 2
2A1-2A8	
1B1-1B8	B Port I/O Byte 1 and Byte 2
2B1-2B8	

Truth Tables

(Note 1)

	Input	Output	Mode		
OEAB	LEAB	CLK	Α	В	
Н	Х	Х	Х	Z	High Impedance
L	Н	Χ	L	L	Transparent
L	Н	Χ	Н	Н	Transparent
L	L	1	L	L	Registered
L	L	↑	Н	н	Registered
L	L	Н	Х	B ₀ (Note 2)	Previous State
L	L	L	X	B ₀ (Note 3)	Previous State

	Inputs	Out	puts	
ŌĒ	OEAB (Note 4)	OEBA (Note 4)	A Port	B Port
L	L	L	Active	Active
L	L	Н	Z	Active
L	Н	L	Active	Z
L	Н	Н	Z	Z
Н	Х	Х	Z	Z

Inputs	Output Edge
V _{ERC}	B Port
V _{CC}	Slow
GND	Fast

Note 1: A-to-B data flow is shown. B-to-A data flow is similar but uses $\overline{\text{OEBA}}$, LEBA, CLK.

Note 2: Output level before the indicated steady state input conditions were established, provided CLK was HIGH prior to LEAB going LOW.

Note 3: Output level before the indicated steady state input conditions were established.

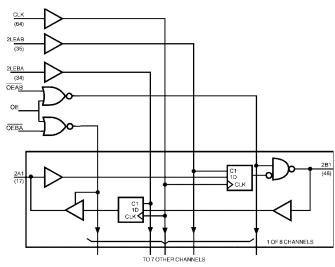
 $\textbf{Note 4: } \overline{\mathsf{OEAB}} \text{ and } \overline{\mathsf{OEBA}} \text{ are byte-wide enables. Each is proceeded by a number indicating the byte controlled.}$

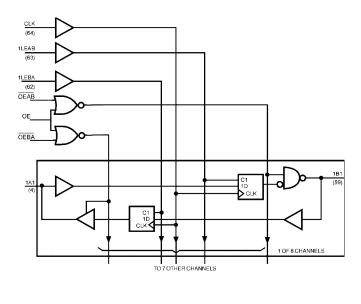
Functional Description

The GTLP16T1655 is a high drive (100 mA) 16-bit universal bus transceiver containing D-type flip-flop, latch and transparent modes of operation for the data path. The device is uniquely partitioned as two 8-bit transceivers with individual latch timing and output control signals but with a common clock pin (CLK) for both transceiver words. Data flow for each word is determined by the respective latch enables (xLEAB and xLEBA), output enables (xOEAB and xOEBA) and clock (CLK). The output enables (10EAB, 10EBA, and 20EAB and 20EBA) control Byte1 and Byte2 data for the A to B and B to A directions respectively.

For A-to-B data flow, the devices operate in the transparent mode when LEAB is HIGH. When LEAB transitions LOW, the A data is latched independent of CLK HIGH or LOW. If LEAB is LOW the A data is registered on the CLK LOW-to-HIGH transition. When OEAB is LOW the outputs are active. With OEAB HIGH the outputs are HIGH impedance. Data flow for the B-to-A direction is identical but uses OEBA, LEBA and CLK. Note that CLK is common to both directions and both 8-bit words. OE is also common and is used to disable all I/O ports simultaneously.

Logic Diagrams





Absolute Maximum Ratings(Note 5) **Recommended Operating Conditions** Supply Voltage (V_{CC}) -0.5V to +4.6V

DC Input Voltage (V_I) -0.5V to +4.6V DC Output Voltage (V_O) Outputs 3-STATE -0.5V to +4.6VOutputs Active (Note 6) -0.5V to +4.6VDC Output Sink Current into A Port I_{OL} DC Output Source Current from A Port IOH -48 mA DC Output Sink Current into B Port in the LOW State, 200 mA I_{OL} (Note 7) DC Input Diode Current (I_{IK}) $V_{I} < 0 \, V$ -50 mA DC Output Diode Current (I_{OK}) $V_O < 0V$ –50 mA $V_O > V_{CC}$ +50 mA **ESD** Rating >2000V

Supply Voltage V_{CC} 3.0V to 3.6V Bus Termination Voltage (V_{TT})

GTLP 1.35V to 1.65V GTL 1.14V to 1.26V

 V_{REF}

48 mA **GTLP** 0.87V to 1.1V

0.74V to 0.87V

Input Voltage (V_I)

-65°C to +150°C

on A Port and Control Pins 0.0V to $V_{\mbox{\footnotesize CC}}$ on B Port 0.0V to V_{tt}

HIGH Level Output Current (I_{OH})

-24 mA

LOW Level Output Current (IOI)

A Port +24mA

B Port +100 mA Operating Temperature (T_A) -40°C to +85°C

Note 5: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 6: In Absolute Maximum Rating must be observed.

Note 7: V_{TT} and R_{term} can be adjusted to accommodate backplane impedances other than $50\Omega,$ within the boundaries of not exceeding the DC Absolute $I_{\mbox{\scriptsize OL}}$ ratings (200 mA). Similarly $V_{\mbox{\scriptsize REF}}$ can be adjusted to compensate for changes in V_{TT}.

DC Electrical Characteristics

Storage Temperature (T_{STG})

Over Recommended Operating Free-Air Temperature Range, $V_{REF} = 1.0V$ (unless otherwise noted).

;	Symbol	Test Co	nditions	Min	(Note 8)	Мах	Units
V _{IH}	B Port			V _{REF} +0.05		V _{TT}	V
	Others			2.0			V
V _{IL}	B Port			0.0		V _{REF} -0.05	V
	Others					0.8	V
V_{REF}	GTLP			0.74	1.0	1.1	V
V _{IK}		V _{CC} = 3.0V	$I_I = -18 \text{ mA}$			-1.2	V
V _{OH}	A Port	V _{CC} = Min to Max (Note 9)	$I_{OH} = -100 \mu A$	V _{CC} −0.2			
		V _{CC} = 3.0V	I _{OH} = -12 mA	2.4			V
			$I_{OH} = -24 \text{ mA}$	2.2			
V _{OL}	A Port	V _{CC} = Min to Max (Note 9)	$I_{OL} = 100 \mu A$			0.20	
		V _{CC} = 3.0V	I _{OL} = 12 mA			0.40	V
			$I_{OL} = 24 \text{ mA}$			0.50	
	B Port	V _{CC} = 3.0V	$I_{OL} = 40 \text{ mA}$			0.20	
			$I_{OL} = 80 \text{ mA}$			0.40	V
			$I_{OL} = 100 \text{ mA}$			0.50	
l _l	A Port	V _{CC} = 3.6V	$V_I = V_{CC}$ or $0V$			±10	μΑ
	Control Pins	V _{CC} = 3.6V	$V_I = V_{CC}$ or $0V$			±10	μΑ
	B Port	V _{CC} = 3.6V	$V_I = V_{TT}$ or GND			±10	μΑ
I _{OFF}	Except	V _{CC} = 0	V_I or $V_O = 0$ to			100	
	V_{ERC}		V _{CC}				μΑ
I _{I(hold)}	A Port	V _{CC} = 3.0V	$V_{I} = 0.8V$	75			
			$V_I = 2.0V$	-75			μΑ
		V _{CC} = 3.6V	$V_I = 0$ to V_{CC}			±500	

DC Electrical Characteristics (Continued)

Sy	mbol		st Conditions	Min	Typ (Note 8)	Max	Units
I _{OZH}	A Port	$V_{CC} = 3.6V$	$V_O = V_{CC}$			10	μА
	B Port		V _O = 1.5V			10	Ι μ.
I _{OZL}	A Port	V _{CC} = 3.6V	$V_O = 0V$			-10	μА
	B Port		$V_0 = 0.4V$			-10	μΑ
I _{OZPU}	A Port	V _{CC} = 0 to 1.5V	V _O = 0.5 to 3V			±50	μΑ
(Note 10)		$\overline{OE} = 0$ or V_{CC}					
I _{OZPD}	A Port	V _{CC} = 1.5 to 0V	V _O = 0.5 to 3V			±50	μΑ
(Note 10)		$\overline{OE} = 0$ or V_{CC}					
I _{CC}	A or B Ports	V _{CC} = 3.6	Outputs HIGH			55	
(v _{cc})		$I_O = 0$	Outputs LOW			55	mA
		$V_I = V_{CC}$ or GND	Outputs Disabled			55	İ
ΔI_{CC}	A Port and	V _{CC} = 3.6V	One Input at		0	1	
(Note 11)	Control Pins	A or Control	V _{CC} -0.6				mA
		Inputs at V _{CC} or GND					
C _i	Control Pins		$V_I = V_{CC}$ or 0		5.8	7.0	
	A Port		$V_I = V_{CC}$ or 0		8.0	9.5	pF
	B Port		$V_I = V_{CC}$ or 0		8.3	9.9	İ

Note 8: All typical values are at $V_{CC} = 3.3V$, and $T_A = 25$ °C.

Note 9: For conditions shown as Min or Max, use the appropriate value specified under recommended operating conditions.

Note 10: This is specified by characterization but not tested.

 $\textbf{Note 11:} \ \textbf{This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.}$

Live Insertion Characteristics

Over Recommended Operating Free-Air Temperature Range, $V_{\mbox{REF}} = 1.0 \mbox{V}$ (unless otherwise noted).

Para	meter	Test Conditions		Min	Тур	Тур Мах	
I _{CC}	B Port	V _{CC} = 0 to 3V	V _O = 0 to 1.2V			5	mA
(V _{CC} BIAS)		V _{CC} = 3.0 to 3.6V	$V_{I}(V_{CC}BIAS) = 3 \text{ to } 3.6V$			10	μΑ
Vo	B Port	$V_{CC} = 0$ $V_1 (V_{CC}BIAS) = 3.3v$			1.1		٧
I _O	B Port	$V_{CC} = 0$ $V_{I} (V_{CC}BIAS) = 3 \text{ to } 3$	-1				
		V _{CC} = 0 to 3.6V $\overline{\text{OE}}$ = 3.3V				100	μΑ
		$V_{CC} = 0 \text{ to } 1.5V$ $\overline{OE} = 0 \text{ to } 3.3$	V			100	

AC Operating Requirements (GTLP)

Over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5V$ and $V_{ref} = 1.0V$ (unless otherwise noted).

	Parameter			Max	Unit
f _{MAX}	Maximum Clock Frequency		160		MHz
t _{WIDTH}	Pulse Duration	LE HIGH	3.0		
		CLK HIGH or LOW	3.0		ns
t _{SU}	Setup Time	Data before CLK↑	2.5		
		Data before LE↓ (CLK = X)	2.5		ns
t _{HOLD}	Hold Time	Data after CLK↑	0.5		
		Data after LE↓ (CLK = X)	0.5		ns

B to A AC Electrical Characteristics (GTLP)

Over recommended range of supply voltage and operating free-air temperature, $V_{REF} = 1.0V$, $V_{TT} = 1.5V$, $V_{ERC} = V_{CC}$ or GND (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Parameter	From	То	Min	Тур	Max	Unit
	(Input)	(Output)		(Note 12)		
f _{MAX}			160			MHz
t _{PLH}	В	А	1.0		4.7	
t _{PHL}			1.5		4.8	ns
t _{PLH}	LEAB	А	1.2		4.0	
t _{PHL}			1.2		3.8	ns
t _{PLH}	CLK	А	1.2		4.0	
t _{PHL}			1.2		4.0	ns
t _{PLZ/HZ}	ŌĒ	А	1.4		4.5	
t _{PZH/ZL}			1.0		4.0	ns
t _{PLZ/HZ}	OEBA	А	1.2		4.9	20
t _{PZH/ZL}			1.0		4.0	ns

Note 12: All typical values are at $V_{CC} = 3.3V$, and $T_A = 25^{\circ}C$.

A to B AC Electrical Characteristics (GTLP)

Over recommended range of supply voltage and operating free air temperature, V = 1.0V, $V_{TT} = 1.5V$ (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

	From	То	Min	Туре	Max	Units
Symbol	(Input)	(Output)		(Note 13)		
f _{MAX}			160			MHz
t _{PLH}	A	В	2.6		5.7	
t _{PHL}	$V_{ERC} = V_{CC}$		0.8		4.5	ns
t _{PLH}	A	В	2.0		4.9	
t _{PHL}	V _{ERC} = GND		0.7		4.0	ns
t _{PLH}	LEAB	В	2.6		5.7	
t _{PHL}	$V_{ERC} = V_{CC}$		0.8		4.0	ns
t _{PLH}	LEAB	В	2.2		4.9	
t _{PHL}	$V_{ERC} = GND$		0.7		4.0	ns
t _{PLH}	CLK	В	2.8		5.7	
t _{PHL}	$V_{ERC} = V_{CC}$		1.0		4.0	ns
t _{PLH}	CLK	В	2.3		5.0	
t _{PHL}	V _{ERC} = GND		0.8		4.0	ns
t _{PLH}	ŌĒ	В	2.7		5.8	
t _{PHL}	$V_{ERC} = V_{CC}$		0.6		4.0	ns
t _{PLH}	ŌĒ	В	2.1		4.9	
t _{PHL}	V _{ERC} = GND		1.0		4.0	ns
t _{PLH}	OEAB	В	2.6		5.8	
t _{PHL}	$V_{ERC} = V_{CC}$		0.6		4.0	ns
t _{PLH}	OEAB	В	2.0		4.9	
t _{PHL}	V _{ERC} = GND		0.6		3.5	ns
t _{FALL/RISE}	Transition Time, B outputs (0.6V to 1.3V)		0.7/0.7	2.0/2.5		20
$V_{ERC} = V_{CC}$	Transmon Time, E	ο ομιραίο (σ.ον το 1.ον)	0.7/0.7	2.0/2.5		ns
t _{FALL/RISE} $V_{ERC} = GND$	Transition Time, E	outputs (0.6V to 1.3V)	0.7/0.7	1.5/2.0		ns

Note 13: All Typical values are at $V_{CC} = 3.3V$ and $T_A = 25^{\circ}C$

Extended Electrical Characteristics (GTLP)

Over recommended ranges of supply voltage and operating free-air temperature $V_{REF} = 1.0V$ (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Symbol	From	То	Min	Тур	Max	Unit
	(Input)	(Output)		(Note 14)		
t _{OSLH} (Note 15)	A	В		0.4	1.0	ns
t _{OSHL} (Note 15)				0.4	1.0	ns
t _{PV(HL)} (Note 16) (Note 17)	A	В			1.5	ns
t _{OSLH} (Note 15)	CLKAB	В		0.3	0.9	ns
t _{OSHL} (Note 15)				0.3	0.6	ns
t _{PV(HL)} (Note 16)(Note 17)	CLKAB	В			1.2	ns
t _{OSLH} (Note 15)	В	Α		0.3	1.0	ns
t _{OSHL} (Note 15)				0.3	1.0	ns
t _{OST} (Note 15)	В	Α		0.6	1.5	ns
t _{PV} (Note 16)	В	Α			1.6	ns
t _{OSLH} (Note 15)	CLKAB	Α		0.3	0.6	ns
t _{OSHL} (Note 15)				0.3	0.6	ns
t _{OST} (Note 15)	CLKAB	Α		0.5	1.0	ns
t _{PV} (Note 16)	CLKAB	Α			1.1	ns

Note 14: All typical values are at $V_{CC}=3.3V$, and $T_A=25^{\circ}C$.

Note 15: t_{OSHL}/t_{OSLH} and t_{OST}—Output to output skew is defined as the absolute value of the difference between the actual propagation delay for all outputs within the same packaged device. The specifications are given for specific worst case V_{CC} and temperature and apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}) or in opposite directions both HL and LH (t_{OST)}. This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTLP outputs could vary on the backplane due to the loading and impedance seen by the device

Note 16: t_{PV}—Part to part skew is defined as the absolute value of the difference between the actual propagation delay for all outputs from device to device. The parameter is specified for a specific worst case V_{CC} and temperature. This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTLP outputs could vary on the backplane due to the loading and impedance seen by the device.

Note 17: Due to the open drain structure on GTLP outputs, t_{OST} and $t_{PV(LH)}$ in the A-to-B direction are not specified. Skew on these paths is dependent on the V_{TT} and R_T values on the backplane.

AC Operating Requirements (GTL)

Over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.2V$ and $V_{ref} = 0.8V$ (unless otherwise noted).

Parameter			Min	Max	Units
f _{MAX}	Maximum Clock Frequency		160		MHz
t _{WIDTH}	Pulse Duration	LE HIGH	3.0		ns
		CLK HIGH or LOW	3.0		ns
t _{SU}	Setup Time	Data before CLK↑	2.5		ns
		Data before LE↓ (CLK = X)	2.5		115
t _{HOLD}	Hold Time	Data after CLK↑	0.5		20
		Data after LE↓ (CLK =X)	0.5		ns

B to A AC Electrical Characteristics (GTL)

Over recommended range of supply voltage and operating free air temperature, $V_{ref} = 0.8V$, $V_{TT} = 1.2V$, $V_{ERC} = V_{CC}$ or GND (unless otherwise noted). $C_L = 30pF$ for B Port and $C_L = 50pF$ for A Port.

Parameter	From	To	Min	Typ	Max	Units
	(Input)	(Output)		(Note 18)		
f_{MAX}			160			MHz
t _{PLH}	В	А	1.0		4.7	ns
t _{PHL}			1.2		4.8	
t _{PLH}	LEBA	А	1.0		4.4	ns
t _{PHL}			1.1		4.0	
t _{PLH}	CLK	А	1.0		4.2	ns
t _{PHL}			1.1		4.1	
t _{PLZ/HZ}	ŌĒ	А	1.5		4.6	ns
t _{PZH/ZL}			1.2		4.2	
t _{PLZ/HZ}	OEBA	А	1.2		4.9	ns
t _{PZH/ZL}			1.0		4.0	

Note 18: All Typical values are at $V_{CC} = 3.3V$ and $T_A = 25^{\circ}C$.

Over recommended range of supply voltage and operating free air temperature, $V_{REF} = 0.8V$, $V_{TT} = 1.2V$ (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Symbol	From	То	Min	Тур	Max	Units
Symbol	(Input)	(Output)		(Note 19)		
MAX			160			MHz
PLH	А	В	2.2		5.7	
PHL	$V_{ERC} = V_{CC}$		1.0		4.7	ns
PLH	Α	В	1.5		4.8	
PHL	$V_{ERC} = GND$		0.9		4.0	ns
PLH	LEAB	В	2.2		5.7	
PHL	$V_{ERC} = V_{CC}$		1.0		4.1	ns
PLH	LEAB	В	1.7		5.0	
PHL	$V_{ERC} = GND$		0.9		4.4	ns
PLH	CLK	В	2.8		5.8	
PHL	$V_{ERC} = V_{CC}$		1.0		4.3	ns
PLH	CLK	В	2.3		5.0	
PHL	$V_{ERC} = GND$		1.0		4.3	ns
PLH	ŌE	В	2.5		5.8	
PHL	$V_{ERC} = V_{CC}$		0.8		4.3	ns
PLH	ŌĒ	В	1.7		4.9	
PHL	$V_{ERC} = GND$		0.9		4.3	ns
PLH	OEAB	В	2.2		5.8	
PHL	$V_{ERC} = V_{CC}$		0.8		4.3	ns
PLH	OEAB	В	1.7		4.9	
PHL	$V_{ERC} = GND$		0.9		3.8	ns
FALL/RISE	Transition Time, B outputs (0.6V to 1.3V)		0.7/0.7	2.0/2.5		ne
V _{ERC} = V _{CC}			0.770.7	2.0/2.3		ns
FALL/RISE V _{ERC} = V _{CC}	Transition Time, B outputs (0.6V to 1.3V)		0.7/0.7	1.5/2.0		ns

Note 19: All Typical values are at $V_{CC} = 3.3V$ and $T_A = 25^{\circ}C$.

Extended Electrical Characteristics (GTL)

Over recommended ranges of supply voltage and operating free-air temperature $V_{REF} = 0.8V$ (unless otherwise noted). $C_L = 30~pF$ for B Port and $C_L = 50~pF$ for A Port.

Symbol	From	То	Min	Тур	Max	Unit
	(Input)	(Output)		(Note 20)		
t _{OSLH} (Note 21)	A	В		0.4	1.0	ns
t _{OSHL} (Note 21)				0.4	1.0	ns
t _{PV(HL)} (Note 22) (Note 23)	A	В			1.5	ns
t _{OSLH} (Note 21)	CLKAB	В		0.3	0.9	ns
t _{OSHL} (Note 21)				0.3	0.6	ns
t _{PV(HL)} (Note 22)(Note 23)	CLKAB	В			1.2	ns
t _{OSLH} (Note 21)	В	Α		0.3	1.0	ns
t _{OSHL} (Note 21)				0.3	1.0	ns
t _{OST} (Note 21)	В	Α		0.6	1.5	ns
t _{PV} (Note 22)	В	Α			1.6	ns
t _{OSLH} (Note 21)	CLKAB	Α		0.3	0.6	ns
t _{OSHL} (Note 21)				0.3	0.6	ns
t _{OST} (Note 21)	CLKAB	Α		0.5	1.0	ns
t _{PV} (Note 22)	CLKAB	Α			1.1	ns

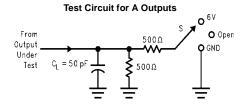
Note 20: All typical values are at $V_{CC}=3.3V$, and $T_A=25^{\circ}C$.

Note 21: t_{OSHL}/t_{OSLH} and t_{OST}—Output to output skew is defined as the absolute value of the difference between the actual propagation delay for all outputs within the same packaged device. The specifications are given for specific worst case V_{CC} and temperature and apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}) or in opposite directions both HL and LH (t_{OST)}. This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTL outputs could vary on the backplane due to the loading and impedance seen by the device

Note 22: t_{PV}—Part to part skew is defined as the absolute value of the difference between the actual propagation delay for all outputs from device to device. The parameter is specified for a specific worst case V_{CC} and temperature. This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTL outputs could vary on the backplane due to the loading and impedance seen by the device.

Note 23: Due to the open drain structure on GTL outputs, t_{OST} and $t_{PV(LH)}$ in the A-to-B direction are not specified. Skew on these paths is dependent on the V_{TT} and R_T values on the backplane.

Test Circuits and Timing Waveforms



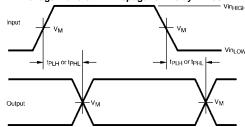
 $\begin{tabular}{lll} \textbf{Test} & \textbf{S} \\ t_{PLH}/t_{PHL} & Open \\ t_{PLZ}/t_{PZL} & 6V \\ t_{PHZ}/t_{PZH} & GND \\ \end{tabular}$

Test Circuit for B Outputs

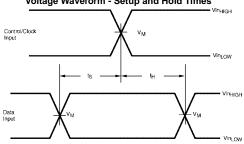


Note A: C_L includes probes and Jig capacitance. Note B: For B Port, C_L = 30 pF is used fort worst case.

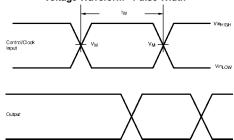
Voltage Waveform - Propagation Delay Times



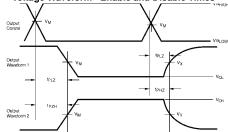
Voltage Waveform - Setup and Hold Times



Voltage Waveform - Pulse Width



Voltage Waveform - Enable and Disable Times



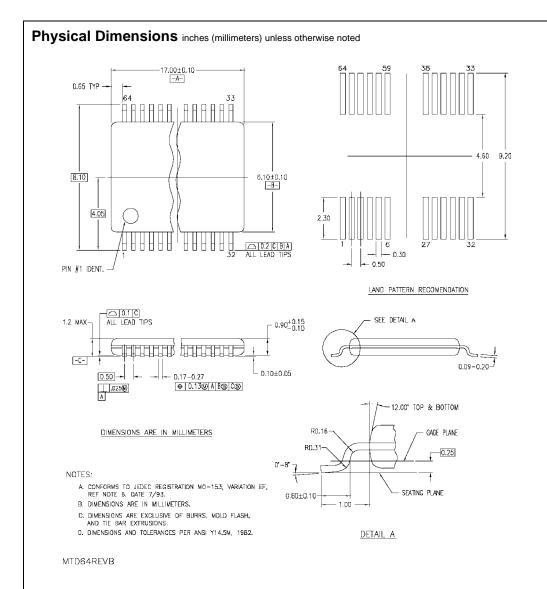
Output Waveform 1 is for an output with internal conditions such that the output is LOW except when disabled by the control output

Output Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the control output

Input and Measure Conditions

	A or LVTTL Pins	B or GTLP Pins
V _{inHIGH}	3.0	1.5
V _{inLOW}	0.0	0.0
V_{M}	1.5	1.0
V _X	$V_{OL} + 0.3V$	N/A
V _Y	V _{OH} – 0.3V	N/A

All input pulses have the following characteristics: Frequency = 10MHz, t_{RISE} = t_{FALL} = 2 ns, Z_{O} = 50Ω The outputs are measured one at a time with one transition per measurement



64-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD64

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